

# PRODUCT SPECIFICATION

**PRODUCT: MULTILAYER CERAMIC CAPACITOR**

**TYPE: RADIAL-LEADED TYPE CAPACITOR**

**CUSTOMER: \_\_\_\_\_**

**DOC. NO.: D13-00-E-09**

**Ver.: 09**

**APPROVED BY CUSTOMER**

**VENDOR :**

**WALSIN TECHNOLOGY CORPORATION**

566-1, KAO SHI ROAD, YANG-MEI  
TAO-YUAN, TAIWAN

**PAN OVERSEAS (GUANGZHOU) ELECTRONIC CO.,LTD.**

NO.277,HONG MING ROAD,EASTERN SECTION,  
GUANG ZHOU ECONOMIC AND TECHNOLOGY  
DEVELOPMENT ZONE,CHINA

**MAKER : PAN OVERSEAS (GUANGZHOU) ELECTRONIC CO.,LTD.**

NO.277,HONG MING ROAD,EASTERN SECTION,  
GUANG ZHOU ECONOMIC AND TECHNOLOGY  
DEVELOPMENT ZONE,CHINA



**Record of change**

<b>Date</b>	<b>Version</b>	<b>Description</b>	<b>page</b>
2009.6.24	3	1. Add voltage code in Marking.	14
2009.8.17	4	1. Change PSA & POE logo to Walsin & POE logo.	all
2012/5/31	5	1. Review the capacitance range.	13~14
2012/11/20	6	1. Add "Table of contents". 2. Review the body size W/H/T according to the chip size. 3. Review the contents of description. 4. Correct the size of P1 for type RD20.	3 4 11 13
2013/5/6	7	1. Review the Lead diameter $\phi$ from $0.55\pm 0.05\text{mm}$ to $0.5+/-0.05\text{mm}$ 2. Add "H1 max" to lead configuration and size form. 3. Review the Solderability temperature from $235\pm 5^{\circ}\text{C}$ to $245\pm 5^{\circ}\text{C}$ ., Solderability time from $2\pm 0.5\text{s}$ to $5\pm 0.5\text{s}$ "	4,12,13 4 8
2014/8/8	8	1. Review the item 8 from "Storing condition and term" to be "Operating and storage environment" 2. Delete the 1206size for RD20 type. 3. Delete the 500V ~630V type of 0805 size. 4. Review the D.F. spec according to MLCC spec of Walsin.	11 4 14 6,8,9,10
2015/11/24	9	1. Review the Part number defining. 2. Add the 1812 size for RD21 type. 3. Add the 1812 size for the D.F. spec according to MLCC spec of Walsin. 4. Review the Packing quantity. 5. Add voltage code in Marking for 2000V&3000V.	4 4 6,8,9,10 14 15

## Table of Contents 目錄

No.	Item 項目	Page
1	Scope	4
2	Part number defining	4
3	Lead configuration and size	4
4	Product structure	5
5	Test conditions	5
6	Handle procedure	5
7	Specification and test method	6~11
8	Storing condition and term	11
9	Description	11
10	Features	11
11	Taping Figure and Specification(RD21)	12
12	Taping Figure and Specification(RD20)	13
13	Packing quantity	14
14	Size code and capacitance (pF) available	14~15
15	Marking	15

### 1. Scope:

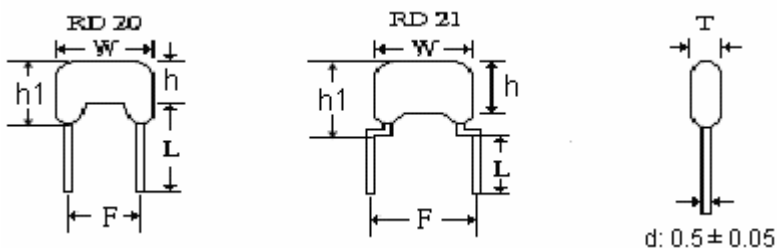
Its specification applies to Radial Series Ceramic Capacitor.

### 2. Part number defining (SAP):

RD21	B				102	K	500	B	5	C	07	B
Product Type	Dielectric Code				Capacitance Code	Tolerance Code	Rated Voltage	Packaging Code	Chip Size	Termination	Lead length	Lead length Tolerance
RD20	Code	T.C.	Operating Temperature	Capacitance Change( $\Delta$ °C)	100=10 pF 102=1000 pF	C= $\pm 0.25$ pF D= $\pm 0.5$ pF	100=10V 250=25V	B=Bulk	5=0805	L=Ag/Ni/Sn C=Cu/Ni/Sn	Tapping: AN=Ammono	D=Tapping
RD21	N	NPO	-55 ~ +125 °C	0 $\pm 30$ (PPM/°C)	103=10000 pF 1R5=1.5 pF	J= $\pm 5$ % K= $\pm 10$ % M= $\pm 20$ % Z= $+80$ % /-20%	500=50V 101=100V 201=200V 251=250V	A=Ammono	6=1206 0=1210	A=Ag/Ni/Sn Halogen free H=Cu/Ni/Sn Halogen free	Bulk (ex): 07=7.0 mm	A= $\pm 0.5$ mm B= $\pm 1$ mm C=Min
	B	X7R	-55 ~ +125 °C	$\pm 15$ %	101=100 pF 472=4700 pF		501=500V 631=630V 102=1000V 202=2000V 302=3000V		2=1812			
	F	Y5V	-25 ~ +85 °C	+30% ~ -80%	104=100000 pF							

\* Remark about tolerance code: NPO: all tolerance, X7R: K、M, Y5V: M、Z

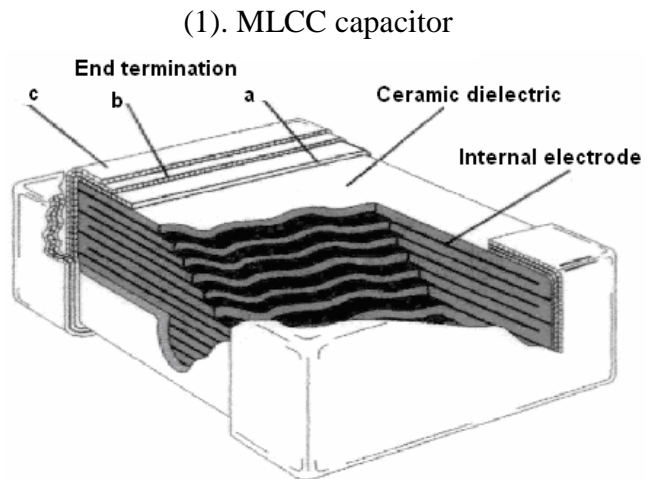
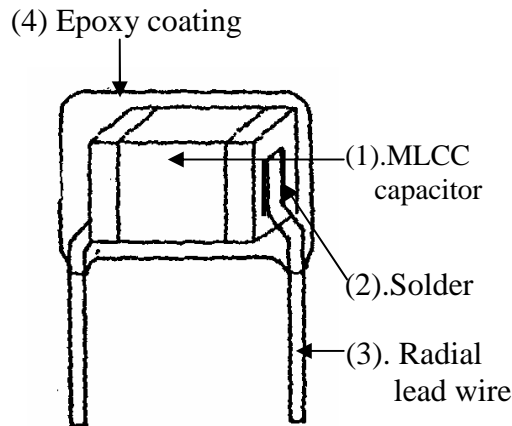
### 3. Lead configuration and size: (Unit: mm)



Type Code	Chip size	Width (W)Max.	Height (Max.)		Thickness (T)Max.	Lead length (L)	Lead spacing for Taping (F)	Lead spacing for Bulk (F)	Lead diameter(d)
			h	h1					
RD20	0805	5.0	4.5	6.0	3.5	Refer to the item "2.2 SAP Part Number"	2.5 $\pm 0.8$	2.54 $\pm 1.0$	0.5 $\pm 0.05$
RD21	0805	5.0	4.5	6.5	3.5		5.0 $\pm 0.8$	5.08 $\pm 1.0$	
	1206	6.5	5.0	7.0	4.0				
	1210 (Special size)	6.5	5.5	7.5	5.0				
	1812	8.0	6.5	8.5	5.5				

**4. Product structure:**

Radial capacitor



NO	Part name	Material	
(1)	MLCC capacitor	Ceramic dielectric	
		Internal Electrode	Ag-Pd or Ni (BME)
		End Termination	Ag or Cu (BME) layer
			Ni layer
(2)	Solder	Tin-silver	
(3)	Radial Lead Wire	Tined CP wire	
(4)	Coating	Epoxy resin(Blue)	

**5. Test conditions:**

Tests shall, unless otherwise specified, be carried out at 15 to 35°C and RH 45 to 75%. If any doubt and argument has been encountered in judgement, the final test shall be done at 25±2°C, RH45 to 55% and 860~1060mbar. (Based on JIS standard)

**6. Handle procedure:**

To avoid unexpected testing results from occurring, the tested capacitor must be kept at room temperature for at least 30 minutes and completely discharged.

**7. Specification and test method :**

No.	Item	Performance	Test or inspection method																																																																																											
(1)	Appearance structure size	No defects which may affect performance.	As section 3																																																																																											
(2)	Withstand Voltage	Withstand test voltage without Insulation breakdown or other damage.	DC Tested voltage shall be applied for 1~5sec. Charge/discharge current shall not exceed 50 mA . <table border="1" style="margin-left: 20px;"> <thead> <tr> <th>Rated Voltage</th> <th>Tested Voltage</th> </tr> </thead> <tbody> <tr> <td>&lt;100V</td> <td>2.5Ra</td> </tr> <tr> <td>100V</td> <td>3.0Ra</td> </tr> <tr> <td>200~300V</td> <td>2.0 Ra</td> </tr> <tr> <td>500~999V</td> <td>1.5 Ra</td> </tr> <tr> <td>1000~3000V</td> <td>1.2 Ra</td> </tr> </tbody> </table>	Rated Voltage	Tested Voltage	<100V	2.5Ra	100V	3.0Ra	200~300V	2.0 Ra	500~999V	1.5 Ra	1000~3000V	1.2 Ra																																																																															
Rated Voltage	Tested Voltage																																																																																													
<100V	2.5Ra																																																																																													
100V	3.0Ra																																																																																													
200~300V	2.0 Ra																																																																																													
500~999V	1.5 Ra																																																																																													
1000~3000V	1.2 Ra																																																																																													
(3)	Insulation resistance	NPO: $10,000M\Omega$ Min. or $500\Omega \cdot F$ Min X7R、Y5V: $10G\Omega$ Min or $R \cdot C \geq 500\Omega \cdot F$ (Whichever is smaller)	Insulation resistance shall be measured at $120\pm 5$ seconds after rated voltage applied. <table border="1" style="margin-left: 20px;"> <thead> <tr> <th>Rated Voltage</th> <th>Tested Voltage</th> </tr> </thead> <tbody> <tr> <td>&lt;500V</td> <td>1.0 Ra</td> </tr> <tr> <td><math>\geq 500V</math></td> <td>500V</td> </tr> </tbody> </table>	Rated Voltage	Tested Voltage	<500V	1.0 Ra	$\geq 500V$	500V																																																																																					
Rated Voltage	Tested Voltage																																																																																													
<500V	1.0 Ra																																																																																													
$\geq 500V$	500V																																																																																													
(4)	Capacitance	Within the specified tolerance.	Measuring frequency & voltage: NPO : $> 1000pF$ : $1KHz\pm 10\%$ $1.0\pm 0.2 V_{rms}$ $\leq 1000pF$ : $1MHz\pm 10\%$ $1.0\pm 0.2 V_{rms}$ X7R、Y5V : $C \leq 10\mu F$ $1.0\pm 0.2 V_{rms}$ $1KHz\pm 10\%$ $C > 10 \mu F$ $0.5\pm 0.2 V_{rms}$ $120Hz\pm 20\%$																																																																																											
(5)	Dissipation Factor	<table border="1" style="width: 100%;"> <thead> <tr> <th colspan="2">NPO</th> <th colspan="2">Special chip size and capacitance</th> </tr> </thead> <tbody> <tr> <td>More than 30pF:</td> <td><math>Q \geq 1000</math></td> <td></td> <td></td> </tr> <tr> <td>Less than 30pF:</td> <td><math>Q \geq 400+20C</math></td> <td></td> <td></td> </tr> <tr> <th colspan="2">X7R</th> <th colspan="2">Special chip size and capacitance</th> </tr> <tr> <td>Rated vol.</td> <td>DF <math>\leq</math></td> <td></td> <td></td> </tr> <tr> <td><math>\geq 100V</math></td> <td><math>\leq 2.5\%</math></td> <td></td> <td></td> </tr> <tr> <td></td> <td><math>\leq 3\%</math></td> <td>1206 <math>\geq 0.47\mu F</math></td> <td></td> </tr> <tr> <td></td> <td><math>\leq 5\%</math></td> <td>0805 <math>&gt; 0.1\mu F</math>, 1206 <math>&gt; 1\mu F</math></td> <td></td> </tr> <tr> <td>50V</td> <td><math>\leq 2.5\%</math></td> <td></td> <td></td> </tr> <tr> <td></td> <td><math>\leq 3\%</math></td> <td>0805 <math>\geq 0.18\mu F</math>, 1206 <math>\geq 0.47\mu F</math></td> <td></td> </tr> <tr> <td></td> <td><math>\leq 5\%</math></td> <td>1210 <math>\geq 4.7\mu F</math></td> <td></td> </tr> <tr> <td></td> <td><math>\leq 10\%</math></td> <td>0805 <math>\geq 1\mu F</math>, 1206 <math>\geq 2.2\mu F</math>, 1210 <math>\geq 10\mu F</math></td> <td></td> </tr> <tr> <th colspan="2">Y5V</th> <th colspan="2">Special chip size and capacitance</th> </tr> <tr> <td>Rated vol.</td> <td>DF <math>\leq</math></td> <td></td> <td></td> </tr> <tr> <td><math>\geq 50V</math></td> <td><math>\leq 5\%</math></td> <td></td> <td></td> </tr> <tr> <td></td> <td><math>\leq 7\%</math></td> <td>0805 <math>\geq 0.47\mu F</math>, 1206 <math>\geq 4.7\mu F</math></td> <td></td> </tr> <tr> <td>25V</td> <td><math>\leq 5\%</math></td> <td></td> <td></td> </tr> <tr> <td></td> <td><math>\leq 7\%</math></td> <td>0805 <math>\geq 0.33\mu F</math>, 1206 <math>\geq 1\mu F</math>, 1210 <math>\geq 4.7\mu F</math></td> <td></td> </tr> <tr> <td></td> <td><math>\leq 9\%</math></td> <td>1206 <math>\geq 4.7\mu F</math>, 1210 <math>\geq 22\mu F</math></td> <td></td> </tr> <tr> <td>16V (C&lt;1.0<math>\mu F</math>)</td> <td><math>\leq 7\%</math></td> <td></td> <td></td> </tr> <tr> <td>16V (C<math>\geq 1.0\mu F</math>)</td> <td><math>\leq 9\%</math></td> <td></td> <td></td> </tr> <tr> <td></td> <td><math>\leq 12.5\%</math></td> <td>0805 <math>\geq 3.3\mu F</math>; 1206 <math>\geq 10\mu F</math>; 1210 <math>\geq 22\mu F</math>; 1812 <math>\geq 47\mu F</math></td> <td></td> </tr> <tr> <td>10V</td> <td><math>\leq 12.5\%</math></td> <td></td> <td></td> </tr> </tbody> </table>		NPO		Special chip size and capacitance		More than 30pF:	$Q \geq 1000$			Less than 30pF:	$Q \geq 400+20C$			X7R		Special chip size and capacitance		Rated vol.	DF $\leq$			$\geq 100V$	$\leq 2.5\%$				$\leq 3\%$	1206 $\geq 0.47\mu F$			$\leq 5\%$	0805 $> 0.1\mu F$ , 1206 $> 1\mu F$		50V	$\leq 2.5\%$				$\leq 3\%$	0805 $\geq 0.18\mu F$ , 1206 $\geq 0.47\mu F$			$\leq 5\%$	1210 $\geq 4.7\mu F$			$\leq 10\%$	0805 $\geq 1\mu F$ , 1206 $\geq 2.2\mu F$ , 1210 $\geq 10\mu F$		Y5V		Special chip size and capacitance		Rated vol.	DF $\leq$			$\geq 50V$	$\leq 5\%$				$\leq 7\%$	0805 $\geq 0.47\mu F$ , 1206 $\geq 4.7\mu F$		25V	$\leq 5\%$				$\leq 7\%$	0805 $\geq 0.33\mu F$ , 1206 $\geq 1\mu F$ , 1210 $\geq 4.7\mu F$			$\leq 9\%$	1206 $\geq 4.7\mu F$ , 1210 $\geq 22\mu F$		16V (C<1.0 $\mu F$ )	$\leq 7\%$			16V (C $\geq 1.0\mu F$ )	$\leq 9\%$				$\leq 12.5\%$	0805 $\geq 3.3\mu F$ ; 1206 $\geq 10\mu F$ ; 1210 $\geq 22\mu F$ ; 1812 $\geq 47\mu F$		10V	$\leq 12.5\%$	
NPO		Special chip size and capacitance																																																																																												
More than 30pF:	$Q \geq 1000$																																																																																													
Less than 30pF:	$Q \geq 400+20C$																																																																																													
X7R		Special chip size and capacitance																																																																																												
Rated vol.	DF $\leq$																																																																																													
$\geq 100V$	$\leq 2.5\%$																																																																																													
	$\leq 3\%$	1206 $\geq 0.47\mu F$																																																																																												
	$\leq 5\%$	0805 $> 0.1\mu F$ , 1206 $> 1\mu F$																																																																																												
50V	$\leq 2.5\%$																																																																																													
	$\leq 3\%$	0805 $\geq 0.18\mu F$ , 1206 $\geq 0.47\mu F$																																																																																												
	$\leq 5\%$	1210 $\geq 4.7\mu F$																																																																																												
	$\leq 10\%$	0805 $\geq 1\mu F$ , 1206 $\geq 2.2\mu F$ , 1210 $\geq 10\mu F$																																																																																												
Y5V		Special chip size and capacitance																																																																																												
Rated vol.	DF $\leq$																																																																																													
$\geq 50V$	$\leq 5\%$																																																																																													
	$\leq 7\%$	0805 $\geq 0.47\mu F$ , 1206 $\geq 4.7\mu F$																																																																																												
25V	$\leq 5\%$																																																																																													
	$\leq 7\%$	0805 $\geq 0.33\mu F$ , 1206 $\geq 1\mu F$ , 1210 $\geq 4.7\mu F$																																																																																												
	$\leq 9\%$	1206 $\geq 4.7\mu F$ , 1210 $\geq 22\mu F$																																																																																												
16V (C<1.0 $\mu F$ )	$\leq 7\%$																																																																																													
16V (C $\geq 1.0\mu F$ )	$\leq 9\%$																																																																																													
	$\leq 12.5\%$	0805 $\geq 3.3\mu F$ ; 1206 $\geq 10\mu F$ ; 1210 $\geq 22\mu F$ ; 1812 $\geq 47\mu F$																																																																																												
10V	$\leq 12.5\%$																																																																																													

No.	Item	Performance			Test or inspection method			
(6)	Temperature Characteristic of Capacitance	Temperatures Coefficient			The temperature coefficient is determined using the capacitance measured at base temperature as a reference. Test the specimen in a range of maximum and minimum operation temperature that shown as left table. * Base Temp $25 \pm 2^\circ\text{C}$ * Base Temp for Y5V: $20 \pm 2^\circ\text{C}$			
		T.C.	Operating Temperature	Capacitance Change( $\Delta C$ )			Step	Temperature( $^\circ\text{C}$ )
		NPO	$-55 \sim +125^\circ\text{C}$	$0 \pm 30(\text{ppm}/^\circ\text{C})$			1	Base Temp.( $25^\circ\text{C}$ ) $\pm 2^\circ\text{C}$
		X7R	$-55 \sim +125^\circ\text{C}$	$\pm 15\%$			2	Min. Operation Temp. $\pm 2^\circ\text{C}$
		Y5V	$-25 \sim +85^\circ\text{C}$	$+30\% \sim -80\%$			3	Base Temp.( $25^\circ\text{C}$ ) $\pm 2^\circ\text{C}$
		4	Max. Operation Temp. $\pm 2^\circ\text{C}$	5			Base Temp.( $25^\circ\text{C}$ ) $\pm 2^\circ\text{C}$	
(7)	Terminal strength	Tensile strength: No breakdown			Loading weight 0.5 Kgs is applied for $10 \pm 1$ seconds			
		Bending strength: No breakdown			Loading weight 0.25 Kgs is applied Bending back and forth 90 degrees twice			
(8)	Soldering heat resistance	External appearance	No mechanical damage.		Lead wire or terminals shall be immersed (A) up to 2.0 mm from body (B) into the Molten solder of which temperature is $260 \pm 5 - 0^\circ\text{C}$ for $3 \pm 0.5$ sec. Then leave at standard test conditions for $24 \pm 2$ hours, then measured.  *Preconditioning : (only for Class 2): Perform a heat treatment at $150 \pm 0/-10^\circ\text{C}$ for one hour and then let sit for $48 \pm 4$ hours at room temperature.			
	Cap. change ( $\Delta C/C$ )	NPO	$\pm 2.5\%$ or $\pm 0.25 \text{ pF max.}$ Whichever is larger	X7R Y5V				
	D.F.	To meet initial standard value						
	I.R.	To meet initial standard value						

No.	Item	Performance		Test or inspection method																																																									
(9)	Solderability	Lead wire shall be soldered over 75% of the circumfluent direction		To comply with JIS-C-5102 8.4 , the soldering temperature is 245±5°C and dipping time is 5±0.5 seconds. Flux: weight ratio of Rosin 25%																																																									
(10)	Humidity (Steady state)	External appearance	No mechanical damage.	Humidity (Steady state): At temperature 40±2 °C and humidity 90 to 95%RH for 500 + 24/ - 0 hours. Leave the capacitors in ambient condition for the following time before measurement. Class 1 : 24±2 hours. Class 2 : 48±4 hours. * Charge / discharge current shall. not exceed 50 mA. * Preconditioning : (only for Class 2): Apply the rated DC voltage for 1hour at 150 ±5°C. Remove and let sit for 48±4 hours at room temperature. Perform initial measurement.																																																									
		Cap. change (Δ C/C)	NPO: ± 5% or ±0.5 pFmax. (Whichever is larger) X7R: ±12.5% Y5V: ±30%																																																										
		D.F.: NPO: $C \geq 30\text{pF: D.F.} \leq \frac{1}{350}$ $10\text{pF} \leq C < 30\text{pF: D.F.} \leq \frac{1}{275+2.5 * C}$ $C < 10\text{pF: D.F.} \leq \frac{1}{200+10 * C}$ PS: C: Nominal Capacitance (pF)																																																											
		<table border="1"> <thead> <tr> <th rowspan="2">Rated vol.</th> <th rowspan="2">DF ≤</th> <th rowspan="2">Special chip size and capacitance</th> </tr> </thead> <tbody> <tr> <td> <table border="1"> <thead> <tr> <th rowspan="2">X7R</th> <th rowspan="2">Rated vol.</th> <th rowspan="2">DF ≤</th> <th rowspan="2">Special chip size and capacitance</th> </tr> </thead> <tbody> <tr> <td> <table border="1"> <thead> <tr> <th>Rated vol.</th> <th>DF ≤</th> <th>Special chip size and capacitance</th> </tr> </thead> <tbody> <tr> <td rowspan="3">≥ 100V</td> <td>≤ 3%</td> <td></td> </tr> <tr> <td>≤ 6%</td> <td>1206 ≥ 0.47μF</td> </tr> <tr> <td>≤ 7.5%</td> <td>0805 &gt; 0.1μF, 1206 &gt; 1μF</td> </tr> <tr> <td rowspan="4">50V</td> <td>≤ 3%</td> <td></td> </tr> <tr> <td>≤ 6%</td> <td>0805 ≥ 0.18μF, 1206 ≥ 0.47μF</td> </tr> <tr> <td>≤ 10%</td> <td>1210 ≥ 4.7μF</td> </tr> <tr> <td>≤ 20%</td> <td>0805 ≥ 1μF, 1206 ≥ 2.2μF, 1210 ≥ 10μF</td> </tr> <tr> <td rowspan="7">Y5V</td> <td>Rated vol.</td> <td>DF ≤</td> <td>Special chip size and capacitance</td> </tr> <tr> <td rowspan="2">≥ 50V</td> <td>≤ 7.5%</td> <td></td> </tr> <tr> <td>≤ 10%</td> <td>0805 ≥ 0.47μF, 1206 ≥ 4.7μF</td> </tr> <tr> <td rowspan="3">25V</td> <td>≤ 7.5%</td> <td></td> </tr> <tr> <td>≤ 10%</td> <td>0805 ≥ 0.33μF, 1206 ≥ 1μF, 1210 ≥ 4.7μF</td> </tr> <tr> <td>≤ 15%</td> <td>1206 ≥ 4.7μF, 1210 ≥ 22μF</td> </tr> <tr> <td>16V (C &lt; 1.0μF)</td> <td>≤ 10%</td> <td></td> </tr> <tr> <td rowspan="2">16V (C ≥ 1.0μF)</td> <td>≤ 12.5%</td> <td></td> </tr> <tr> <td>≤ 20%</td> <td>0805 ≥ 3.3μF; 1206 ≥ 10μF; 1210 ≥ 22μF; 1812 ≥ 47μF;</td> </tr> <tr> <td>10V</td> <td>≤ 20%</td> <td></td> </tr> </tbody> </table> </td> </tr> <tr> <td></td> <td>I.R.</td> <td colspan="2">1GΩ min. or 50Ω *F (Whichever is smaller)</td> </tr> </tbody> </table> </td></tr></tbody></table>	Rated vol.	DF ≤	Special chip size and capacitance	<table border="1"> <thead> <tr> <th rowspan="2">X7R</th> <th rowspan="2">Rated vol.</th> <th rowspan="2">DF ≤</th> <th rowspan="2">Special chip size and capacitance</th> </tr> </thead> <tbody> <tr> <td> <table border="1"> <thead> <tr> <th>Rated vol.</th> <th>DF ≤</th> <th>Special chip size and capacitance</th> </tr> </thead> <tbody> <tr> <td rowspan="3">≥ 100V</td> <td>≤ 3%</td> <td></td> </tr> <tr> <td>≤ 6%</td> <td>1206 ≥ 0.47μF</td> </tr> <tr> <td>≤ 7.5%</td> <td>0805 &gt; 0.1μF, 1206 &gt; 1μF</td> </tr> <tr> <td rowspan="4">50V</td> <td>≤ 3%</td> <td></td> </tr> <tr> <td>≤ 6%</td> <td>0805 ≥ 0.18μF, 1206 ≥ 0.47μF</td> </tr> <tr> <td>≤ 10%</td> <td>1210 ≥ 4.7μF</td> </tr> <tr> <td>≤ 20%</td> <td>0805 ≥ 1μF, 1206 ≥ 2.2μF, 1210 ≥ 10μF</td> </tr> <tr> <td rowspan="7">Y5V</td> <td>Rated vol.</td> <td>DF ≤</td> <td>Special chip size and capacitance</td> </tr> <tr> <td rowspan="2">≥ 50V</td> <td>≤ 7.5%</td> <td></td> </tr> <tr> <td>≤ 10%</td> <td>0805 ≥ 0.47μF, 1206 ≥ 4.7μF</td> </tr> <tr> <td rowspan="3">25V</td> <td>≤ 7.5%</td> <td></td> </tr> <tr> <td>≤ 10%</td> <td>0805 ≥ 0.33μF, 1206 ≥ 1μF, 1210 ≥ 4.7μF</td> </tr> <tr> <td>≤ 15%</td> <td>1206 ≥ 4.7μF, 1210 ≥ 22μF</td> </tr> <tr> <td>16V (C &lt; 1.0μF)</td> <td>≤ 10%</td> <td></td> </tr> <tr> <td rowspan="2">16V (C ≥ 1.0μF)</td> <td>≤ 12.5%</td> <td></td> </tr> <tr> <td>≤ 20%</td> <td>0805 ≥ 3.3μF; 1206 ≥ 10μF; 1210 ≥ 22μF; 1812 ≥ 47μF;</td> </tr> <tr> <td>10V</td> <td>≤ 20%</td> <td></td> </tr> </tbody> </table> </td> </tr> <tr> <td></td> <td>I.R.</td> <td colspan="2">1GΩ min. or 50Ω *F (Whichever is smaller)</td> </tr> </tbody> </table>	X7R	Rated vol.	DF ≤	Special chip size and capacitance	<table border="1"> <thead> <tr> <th>Rated vol.</th> <th>DF ≤</th> <th>Special chip size and capacitance</th> </tr> </thead> <tbody> <tr> <td rowspan="3">≥ 100V</td> <td>≤ 3%</td> <td></td> </tr> <tr> <td>≤ 6%</td> <td>1206 ≥ 0.47μF</td> </tr> <tr> <td>≤ 7.5%</td> <td>0805 &gt; 0.1μF, 1206 &gt; 1μF</td> </tr> <tr> <td rowspan="4">50V</td> <td>≤ 3%</td> <td></td> </tr> <tr> <td>≤ 6%</td> <td>0805 ≥ 0.18μF, 1206 ≥ 0.47μF</td> </tr> <tr> <td>≤ 10%</td> <td>1210 ≥ 4.7μF</td> </tr> <tr> <td>≤ 20%</td> <td>0805 ≥ 1μF, 1206 ≥ 2.2μF, 1210 ≥ 10μF</td> </tr> <tr> <td rowspan="7">Y5V</td> <td>Rated vol.</td> <td>DF ≤</td> <td>Special chip size and capacitance</td> </tr> <tr> <td rowspan="2">≥ 50V</td> <td>≤ 7.5%</td> <td></td> </tr> <tr> <td>≤ 10%</td> <td>0805 ≥ 0.47μF, 1206 ≥ 4.7μF</td> </tr> <tr> <td rowspan="3">25V</td> <td>≤ 7.5%</td> <td></td> </tr> <tr> <td>≤ 10%</td> <td>0805 ≥ 0.33μF, 1206 ≥ 1μF, 1210 ≥ 4.7μF</td> </tr> <tr> <td>≤ 15%</td> <td>1206 ≥ 4.7μF, 1210 ≥ 22μF</td> </tr> <tr> <td>16V (C &lt; 1.0μF)</td> <td>≤ 10%</td> <td></td> </tr> <tr> <td rowspan="2">16V (C ≥ 1.0μF)</td> <td>≤ 12.5%</td> <td></td> </tr> <tr> <td>≤ 20%</td> <td>0805 ≥ 3.3μF; 1206 ≥ 10μF; 1210 ≥ 22μF; 1812 ≥ 47μF;</td> </tr> <tr> <td>10V</td> <td>≤ 20%</td> <td></td> </tr> </tbody> </table>	Rated vol.	DF ≤	Special chip size and capacitance	≥ 100V	≤ 3%		≤ 6%	1206 ≥ 0.47μF	≤ 7.5%	0805 > 0.1μF, 1206 > 1μF	50V	≤ 3%		≤ 6%	0805 ≥ 0.18μF, 1206 ≥ 0.47μF	≤ 10%	1210 ≥ 4.7μF	≤ 20%	0805 ≥ 1μF, 1206 ≥ 2.2μF, 1210 ≥ 10μF	Y5V	Rated vol.	DF ≤	Special chip size and capacitance	≥ 50V	≤ 7.5%		≤ 10%	0805 ≥ 0.47μF, 1206 ≥ 4.7μF	25V	≤ 7.5%		≤ 10%	0805 ≥ 0.33μF, 1206 ≥ 1μF, 1210 ≥ 4.7μF	≤ 15%	1206 ≥ 4.7μF, 1210 ≥ 22μF	16V (C < 1.0μF)	≤ 10%		16V (C ≥ 1.0μF)	≤ 12.5%		≤ 20%	0805 ≥ 3.3μF; 1206 ≥ 10μF; 1210 ≥ 22μF; 1812 ≥ 47μF;	10V	≤ 20%			I.R.	1GΩ min. or 50Ω *F (Whichever is smaller)	
Rated vol.	DF ≤	Special chip size and capacitance																																																											
			<table border="1"> <thead> <tr> <th rowspan="2">X7R</th> <th rowspan="2">Rated vol.</th> <th rowspan="2">DF ≤</th> <th rowspan="2">Special chip size and capacitance</th> </tr> </thead> <tbody> <tr> <td> <table border="1"> <thead> <tr> <th>Rated vol.</th> <th>DF ≤</th> <th>Special chip size and capacitance</th> </tr> </thead> <tbody> <tr> <td rowspan="3">≥ 100V</td> <td>≤ 3%</td> <td></td> </tr> <tr> <td>≤ 6%</td> <td>1206 ≥ 0.47μF</td> </tr> <tr> <td>≤ 7.5%</td> <td>0805 &gt; 0.1μF, 1206 &gt; 1μF</td> </tr> <tr> <td rowspan="4">50V</td> <td>≤ 3%</td> <td></td> </tr> <tr> <td>≤ 6%</td> <td>0805 ≥ 0.18μF, 1206 ≥ 0.47μF</td> </tr> <tr> <td>≤ 10%</td> <td>1210 ≥ 4.7μF</td> </tr> <tr> <td>≤ 20%</td> <td>0805 ≥ 1μF, 1206 ≥ 2.2μF, 1210 ≥ 10μF</td> </tr> <tr> <td rowspan="7">Y5V</td> <td>Rated vol.</td> <td>DF ≤</td> <td>Special chip size and capacitance</td> </tr> <tr> <td rowspan="2">≥ 50V</td> <td>≤ 7.5%</td> <td></td> </tr> <tr> <td>≤ 10%</td> <td>0805 ≥ 0.47μF, 1206 ≥ 4.7μF</td> </tr> <tr> <td rowspan="3">25V</td> <td>≤ 7.5%</td> <td></td> </tr> <tr> <td>≤ 10%</td> <td>0805 ≥ 0.33μF, 1206 ≥ 1μF, 1210 ≥ 4.7μF</td> </tr> <tr> <td>≤ 15%</td> <td>1206 ≥ 4.7μF, 1210 ≥ 22μF</td> </tr> <tr> <td>16V (C &lt; 1.0μF)</td> <td>≤ 10%</td> <td></td> </tr> <tr> <td rowspan="2">16V (C ≥ 1.0μF)</td> <td>≤ 12.5%</td> <td></td> </tr> <tr> <td>≤ 20%</td> <td>0805 ≥ 3.3μF; 1206 ≥ 10μF; 1210 ≥ 22μF; 1812 ≥ 47μF;</td> </tr> <tr> <td>10V</td> <td>≤ 20%</td> <td></td> </tr> </tbody> </table> </td> </tr> <tr> <td></td> <td>I.R.</td> <td colspan="2">1GΩ min. or 50Ω *F (Whichever is smaller)</td> </tr> </tbody> </table>	X7R	Rated vol.	DF ≤	Special chip size and capacitance	<table border="1"> <thead> <tr> <th>Rated vol.</th> <th>DF ≤</th> <th>Special chip size and capacitance</th> </tr> </thead> <tbody> <tr> <td rowspan="3">≥ 100V</td> <td>≤ 3%</td> <td></td> </tr> <tr> <td>≤ 6%</td> <td>1206 ≥ 0.47μF</td> </tr> <tr> <td>≤ 7.5%</td> <td>0805 &gt; 0.1μF, 1206 &gt; 1μF</td> </tr> <tr> <td rowspan="4">50V</td> <td>≤ 3%</td> <td></td> </tr> <tr> <td>≤ 6%</td> <td>0805 ≥ 0.18μF, 1206 ≥ 0.47μF</td> </tr> <tr> <td>≤ 10%</td> <td>1210 ≥ 4.7μF</td> </tr> <tr> <td>≤ 20%</td> <td>0805 ≥ 1μF, 1206 ≥ 2.2μF, 1210 ≥ 10μF</td> </tr> <tr> <td rowspan="7">Y5V</td> <td>Rated vol.</td> <td>DF ≤</td> <td>Special chip size and capacitance</td> </tr> <tr> <td rowspan="2">≥ 50V</td> <td>≤ 7.5%</td> <td></td> </tr> <tr> <td>≤ 10%</td> <td>0805 ≥ 0.47μF, 1206 ≥ 4.7μF</td> </tr> <tr> <td rowspan="3">25V</td> <td>≤ 7.5%</td> <td></td> </tr> <tr> <td>≤ 10%</td> <td>0805 ≥ 0.33μF, 1206 ≥ 1μF, 1210 ≥ 4.7μF</td> </tr> <tr> <td>≤ 15%</td> <td>1206 ≥ 4.7μF, 1210 ≥ 22μF</td> </tr> <tr> <td>16V (C &lt; 1.0μF)</td> <td>≤ 10%</td> <td></td> </tr> <tr> <td rowspan="2">16V (C ≥ 1.0μF)</td> <td>≤ 12.5%</td> <td></td> </tr> <tr> <td>≤ 20%</td> <td>0805 ≥ 3.3μF; 1206 ≥ 10μF; 1210 ≥ 22μF; 1812 ≥ 47μF;</td> </tr> <tr> <td>10V</td> <td>≤ 20%</td> <td></td> </tr> </tbody> </table>	Rated vol.	DF ≤	Special chip size and capacitance	≥ 100V	≤ 3%			≤ 6%	1206 ≥ 0.47μF	≤ 7.5%	0805 > 0.1μF, 1206 > 1μF	50V	≤ 3%			≤ 6%	0805 ≥ 0.18μF, 1206 ≥ 0.47μF	≤ 10%	1210 ≥ 4.7μF	≤ 20%	0805 ≥ 1μF, 1206 ≥ 2.2μF, 1210 ≥ 10μF	Y5V		Rated vol.	DF ≤	Special chip size and capacitance	≥ 50V	≤ 7.5%		≤ 10%	0805 ≥ 0.47μF, 1206 ≥ 4.7μF		25V	≤ 7.5%		≤ 10%	0805 ≥ 0.33μF, 1206 ≥ 1μF, 1210 ≥ 4.7μF	≤ 15%	1206 ≥ 4.7μF, 1210 ≥ 22μF	16V (C < 1.0μF)	≤ 10%		16V (C ≥ 1.0μF)	≤ 12.5%		≤ 20%	0805 ≥ 3.3μF; 1206 ≥ 10μF; 1210 ≥ 22μF; 1812 ≥ 47μF;	10V	≤ 20%			I.R.	1GΩ min. or 50Ω *F (Whichever is smaller)
X7R	Rated vol.	DF ≤	Special chip size and capacitance																																																										
				<table border="1"> <thead> <tr> <th>Rated vol.</th> <th>DF ≤</th> <th>Special chip size and capacitance</th> </tr> </thead> <tbody> <tr> <td rowspan="3">≥ 100V</td> <td>≤ 3%</td> <td></td> </tr> <tr> <td>≤ 6%</td> <td>1206 ≥ 0.47μF</td> </tr> <tr> <td>≤ 7.5%</td> <td>0805 &gt; 0.1μF, 1206 &gt; 1μF</td> </tr> <tr> <td rowspan="4">50V</td> <td>≤ 3%</td> <td></td> </tr> <tr> <td>≤ 6%</td> <td>0805 ≥ 0.18μF, 1206 ≥ 0.47μF</td> </tr> <tr> <td>≤ 10%</td> <td>1210 ≥ 4.7μF</td> </tr> <tr> <td>≤ 20%</td> <td>0805 ≥ 1μF, 1206 ≥ 2.2μF, 1210 ≥ 10μF</td> </tr> <tr> <td rowspan="7">Y5V</td> <td>Rated vol.</td> <td>DF ≤</td> <td>Special chip size and capacitance</td> </tr> <tr> <td rowspan="2">≥ 50V</td> <td>≤ 7.5%</td> <td></td> </tr> <tr> <td>≤ 10%</td> <td>0805 ≥ 0.47μF, 1206 ≥ 4.7μF</td> </tr> <tr> <td rowspan="3">25V</td> <td>≤ 7.5%</td> <td></td> </tr> <tr> <td>≤ 10%</td> <td>0805 ≥ 0.33μF, 1206 ≥ 1μF, 1210 ≥ 4.7μF</td> </tr> <tr> <td>≤ 15%</td> <td>1206 ≥ 4.7μF, 1210 ≥ 22μF</td> </tr> <tr> <td>16V (C &lt; 1.0μF)</td> <td>≤ 10%</td> <td></td> </tr> <tr> <td rowspan="2">16V (C ≥ 1.0μF)</td> <td>≤ 12.5%</td> <td></td> </tr> <tr> <td>≤ 20%</td> <td>0805 ≥ 3.3μF; 1206 ≥ 10μF; 1210 ≥ 22μF; 1812 ≥ 47μF;</td> </tr> <tr> <td>10V</td> <td>≤ 20%</td> <td></td> </tr> </tbody> </table>	Rated vol.	DF ≤	Special chip size and capacitance	≥ 100V	≤ 3%		≤ 6%		1206 ≥ 0.47μF	≤ 7.5%	0805 > 0.1μF, 1206 > 1μF	50V	≤ 3%		≤ 6%		0805 ≥ 0.18μF, 1206 ≥ 0.47μF	≤ 10%	1210 ≥ 4.7μF	≤ 20%	0805 ≥ 1μF, 1206 ≥ 2.2μF, 1210 ≥ 10μF	Y5V	Rated vol.	DF ≤	Special chip size and capacitance			≥ 50V	≤ 7.5%		≤ 10%	0805 ≥ 0.47μF, 1206 ≥ 4.7μF	25V	≤ 7.5%		≤ 10%		0805 ≥ 0.33μF, 1206 ≥ 1μF, 1210 ≥ 4.7μF	≤ 15%	1206 ≥ 4.7μF, 1210 ≥ 22μF	16V (C < 1.0μF)	≤ 10%		16V (C ≥ 1.0μF)	≤ 12.5%		≤ 20%	0805 ≥ 3.3μF; 1206 ≥ 10μF; 1210 ≥ 22μF; 1812 ≥ 47μF;	10V	≤ 20%							
Rated vol.	DF ≤	Special chip size and capacitance																																																											
≥ 100V	≤ 3%																																																												
	≤ 6%	1206 ≥ 0.47μF																																																											
	≤ 7.5%	0805 > 0.1μF, 1206 > 1μF																																																											
50V	≤ 3%																																																												
	≤ 6%	0805 ≥ 0.18μF, 1206 ≥ 0.47μF																																																											
	≤ 10%	1210 ≥ 4.7μF																																																											
	≤ 20%	0805 ≥ 1μF, 1206 ≥ 2.2μF, 1210 ≥ 10μF																																																											
Y5V	Rated vol.	DF ≤	Special chip size and capacitance																																																										
	≥ 50V	≤ 7.5%																																																											
		≤ 10%	0805 ≥ 0.47μF, 1206 ≥ 4.7μF																																																										
	25V	≤ 7.5%																																																											
		≤ 10%	0805 ≥ 0.33μF, 1206 ≥ 1μF, 1210 ≥ 4.7μF																																																										
		≤ 15%	1206 ≥ 4.7μF, 1210 ≥ 22μF																																																										
	16V (C < 1.0μF)	≤ 10%																																																											
16V (C ≥ 1.0μF)	≤ 12.5%																																																												
	≤ 20%	0805 ≥ 3.3μF; 1206 ≥ 10μF; 1210 ≥ 22μF; 1812 ≥ 47μF;																																																											
10V	≤ 20%																																																												
	I.R.	1GΩ min. or 50Ω *F (Whichever is smaller)																																																											



No.	Item	Performance		Test or inspection method	
(11)	Humidity load	External appearance	No mechanical damage.		Humidity load: ( apply for the product with rated voltage 500V-Max): Apply the rated voltage at temperature $40\pm 2\text{ }^{\circ}\text{C}$ and humidity 90 to 95%RH for 500 +24/ -0 hours. Leave the capacitors in ambient condition for the following time before measurement. Class 1 : $24\pm 2$ hours. Class 2 : $48\pm 4$ hours. * Charge / discharge current shall. not exceed 50 mA. * Preconditioning : (only for Class 2): Apply the rated DC voltage for 1hour at $150\pm 5\text{ }^{\circ}\text{C}$ . Remove and let sit for $48\pm 4$ hours at room temperature. Perform initial measurement.
		Cap. change ( $\Delta C/C$ )	NPO: $\pm 5\%$ or $\pm 0.5\text{ pFmax.}$ (Whichever is larger) X7R: $\pm 12.5\%$ Y5V: $\pm 30\%$		
		D.F.:  NPO: $C \geq 30\text{pF}$ : $D.F. \leq \frac{1}{350}$ $10\text{pF} \leq C < 30\text{pF}$ : $D.F. \leq \frac{1}{275+2.5*C}$ $C < 10\text{pF}$ : $D.F. \leq \frac{1}{200+10*C}$ PS: C: Nominal Capacitance (pF)			
I.R.		$500\text{M}\Omega$ min. or $25\ \Omega *F$ (Whichever is smaller)			

	Rated vol.	DF $\leq$	Special chip size and capacitance
X7R	$\geq 100\text{V}$	$\leq 3\%$	
		$\leq 6\%$	$1206 \geq 0.47\mu\text{F}$
		$\leq 7.5\%$	$0805 > 0.1\mu\text{F}, 1206 > 1\mu\text{F}$
	50V	$\leq 3\%$	
		$\leq 6\%$	$0805 \geq 0.18\mu\text{F}, 1206 \geq 0.47\mu\text{F}$
		$\leq 10\%$	$1210 \geq 4.7\mu\text{F}$
	$\leq 20\%$	$0805 \geq 1\mu\text{F}, 1206 \geq 2.2\mu\text{F}, 1210 \geq 10\mu\text{F}$	
Y5V	$\geq 50\text{V}$	$\leq 7.5\%$	
		$\leq 10\%$	$0805 \geq 0.47\mu\text{F}, 1206 \geq 4.7\mu\text{F}$
	25V	$\leq 7.5\%$	
		$\leq 10\%$	$0805 \geq 0.33\mu\text{F}, 1206 \geq 1\mu\text{F}, 1210 \geq 4.7\mu\text{F}$
		$\leq 15\%$	$1206 \geq 4.7\mu\text{F}, 1210 \geq 22\mu\text{F}$
	16V ( $C < 1.0\mu\text{F}$ )	$\leq 10\%$	
	16V ( $C \geq 1.0\mu\text{F}$ )	$\leq 12.5\%$	
		$\leq 20\%$	$0805 \geq 3.3\mu\text{F}; 1206 \geq 10\mu\text{F}; 1210 \geq 22\mu\text{F}; 1812 \geq 47\mu\text{F};$
10V	$\leq 20\%$		

No.	Item	Performance	Test or inspection method																																											
(12)	Temperature Load	External appearance	No mechanical damage.																																											
		Cap. change ( $\Delta C/C$ )	NPO: $\pm 3\%$ or $\pm 0.3pF_{max}$ . (Whichever is larger) X7R: $\geq 10V$ , $\pm 12.5\%$  Y5V: $\geq 10V$ , $\pm 30\%$																																											
		D.F.:  NPO: $C \geq 30pF$ : D.F. $\leq \frac{1}{350}$ $10pF \leq C < 30pF$ : D.F. $\leq \frac{1}{275 + 2.5 * C}$ $C < 10pF$ : D.F. $\leq \frac{1}{200 + 10 * C}$ PS: C: Nominal Capacitance (pF)	<table border="1"> <thead> <tr> <th>Rated Voltage</th> <th>Tested Voltage</th> </tr> </thead> <tbody> <tr> <td>&lt; 500V</td> <td>2.0Ra</td> </tr> <tr> <td>500V</td> <td>1.5Ra</td> </tr> <tr> <td><math>\geq 630V</math></td> <td>1.2Ra</td> </tr> <tr> <td><math>\geq 1000V</math></td> <td>1.2Ra</td> </tr> </tbody> </table> <p>PS: The test voltage is 150% of rated voltage for below range.</p> <table border="1"> <thead> <tr> <th>Size</th> <th>Rated voltage</th> <th>Capacitance</th> </tr> </thead> <tbody> <tr> <td>0805</td> <td>50V(X7R)</td> <td><math>C \geq 2.2\mu F</math></td> </tr> <tr> <td></td> <td>100V(X7R)</td> <td><math>C \geq 0.47\mu F</math></td> </tr> <tr> <td></td> <td>16V(Y5V)</td> <td><math>C \geq 0.47\mu F</math></td> </tr> <tr> <td>1206</td> <td>100V(X7R)</td> <td><math>C \geq 1.0\mu F</math></td> </tr> </tbody> </table>	Rated Voltage	Tested Voltage	< 500V	2.0Ra	500V	1.5Ra	$\geq 630V$	1.2Ra	$\geq 1000V$	1.2Ra	Size	Rated voltage	Capacitance	0805	50V(X7R)	$C \geq 2.2\mu F$		100V(X7R)	$C \geq 0.47\mu F$		16V(Y5V)	$C \geq 0.47\mu F$	1206	100V(X7R)	$C \geq 1.0\mu F$																		
Rated Voltage	Tested Voltage																																													
< 500V	2.0Ra																																													
500V	1.5Ra																																													
$\geq 630V$	1.2Ra																																													
$\geq 1000V$	1.2Ra																																													
Size	Rated voltage	Capacitance																																												
0805	50V(X7R)	$C \geq 2.2\mu F$																																												
	100V(X7R)	$C \geq 0.47\mu F$																																												
	16V(Y5V)	$C \geq 0.47\mu F$																																												
1206	100V(X7R)	$C \geq 1.0\mu F$																																												
		<table border="1"> <thead> <tr> <th rowspan="2">Rated vol.</th> <th rowspan="2">DF <math>\leq</math></th> <th rowspan="2">Special chip size and capacitance</th> </tr> <tr> <th></th> </tr> </thead> <tbody> <tr> <td rowspan="3"><math>\geq 100V</math></td> <td><math>\leq 3\%</math></td> <td></td> </tr> <tr> <td><math>\leq 6\%</math></td> <td>1206 <math>\geq 0.47\mu F</math></td> </tr> <tr> <td><math>\leq 7.5\%</math></td> <td>0805 <math>&gt; 0.1\mu F</math>, 1206 <math>&gt; 1\mu F</math></td> </tr> <tr> <td rowspan="4">50V</td> <td><math>\leq 3\%</math></td> <td></td> </tr> <tr> <td><math>\leq 6\%</math></td> <td>0805 <math>\geq 0.18\mu F</math>, 1206 <math>\geq 0.47\mu F</math></td> </tr> <tr> <td><math>\leq 10\%</math></td> <td>1210 <math>\geq 4.7\mu F</math></td> </tr> <tr> <td><math>\leq 20\%</math></td> <td>0805 <math>\geq 1\mu F</math>, 1206 <math>\geq 2.2\mu F</math>, 1210 <math>\geq 10\mu F</math></td> </tr> <tr> <td rowspan="7">Y5V</td> <td rowspan="2"><math>\geq 50V</math></td> <td><math>\leq 7.5\%</math></td> <td></td> </tr> <tr> <td><math>\leq 10\%</math></td> <td>0805 <math>\geq 0.47\mu F</math>, 1206 <math>\geq 4.7\mu F</math></td> </tr> <tr> <td rowspan="3">25V</td> <td><math>\leq 7.5\%</math></td> <td></td> </tr> <tr> <td><math>\leq 10\%</math></td> <td>0805 <math>\geq 0.33\mu F</math>, 1206 <math>\geq 1\mu F</math>, 1210 <math>\geq 4.7\mu F</math></td> </tr> <tr> <td><math>\leq 15\%</math></td> <td>1206 <math>\geq 4.7\mu F</math>, 1210 <math>\geq 22\mu F</math></td> </tr> <tr> <td>16V (C &lt; 1.0<math>\mu F</math>)</td> <td><math>\leq 10\%</math></td> <td></td> </tr> <tr> <td rowspan="2">16V (C <math>\geq 1.0\mu F</math>)</td> <td><math>\leq 12.5\%</math></td> <td></td> </tr> <tr> <td><math>\leq 20\%</math></td> <td>0805 <math>\geq 3.3\mu F</math>; 1206 <math>\geq 10\mu F</math>; 1210 <math>\geq 22\mu F</math>; 1812 <math>\geq 47\mu F</math>;</td> </tr> <tr> <td>10V</td> <td><math>\leq 20\%</math></td> <td></td> </tr> </tbody> </table> <p>at maximum operating temperature <math>\pm 2^\circ C</math> for 1000 + 48 / - 0 hours. Leave the capacitors in ambient condition for the following time before measurement.                      Class I: 24 <math>\pm</math> 2 hours                      Class II: 48 <math>\pm</math> 4 hours</p> <p>* Charge / discharge current shall not exceed 50 mA.                      * Preconditioning : (only for Class 2):                      Apply 200% of the rated DC voltage for 1 hour at the maximum operating temperature <math>\pm 3^\circ C</math>.                      Remove and let sit for 48 <math>\pm</math> 4 hours at room temperature. Perform initial measurement.</p>	Rated vol.	DF $\leq$	Special chip size and capacitance		$\geq 100V$	$\leq 3\%$		$\leq 6\%$	1206 $\geq 0.47\mu F$	$\leq 7.5\%$	0805 $> 0.1\mu F$ , 1206 $> 1\mu F$	50V	$\leq 3\%$		$\leq 6\%$	0805 $\geq 0.18\mu F$ , 1206 $\geq 0.47\mu F$	$\leq 10\%$	1210 $\geq 4.7\mu F$	$\leq 20\%$	0805 $\geq 1\mu F$ , 1206 $\geq 2.2\mu F$ , 1210 $\geq 10\mu F$	Y5V	$\geq 50V$	$\leq 7.5\%$		$\leq 10\%$	0805 $\geq 0.47\mu F$ , 1206 $\geq 4.7\mu F$	25V	$\leq 7.5\%$		$\leq 10\%$	0805 $\geq 0.33\mu F$ , 1206 $\geq 1\mu F$ , 1210 $\geq 4.7\mu F$	$\leq 15\%$	1206 $\geq 4.7\mu F$ , 1210 $\geq 22\mu F$	16V (C < 1.0 $\mu F$ )	$\leq 10\%$		16V (C $\geq 1.0\mu F$ )	$\leq 12.5\%$		$\leq 20\%$	0805 $\geq 3.3\mu F$ ; 1206 $\geq 10\mu F$ ; 1210 $\geq 22\mu F$ ; 1812 $\geq 47\mu F$ ;	10V	$\leq 20\%$	
Rated vol.	DF $\leq$	Special chip size and capacitance																																												
$\geq 100V$	$\leq 3\%$																																													
	$\leq 6\%$	1206 $\geq 0.47\mu F$																																												
	$\leq 7.5\%$	0805 $> 0.1\mu F$ , 1206 $> 1\mu F$																																												
50V	$\leq 3\%$																																													
	$\leq 6\%$	0805 $\geq 0.18\mu F$ , 1206 $\geq 0.47\mu F$																																												
	$\leq 10\%$	1210 $\geq 4.7\mu F$																																												
	$\leq 20\%$	0805 $\geq 1\mu F$ , 1206 $\geq 2.2\mu F$ , 1210 $\geq 10\mu F$																																												
Y5V	$\geq 50V$	$\leq 7.5\%$																																												
		$\leq 10\%$	0805 $\geq 0.47\mu F$ , 1206 $\geq 4.7\mu F$																																											
	25V	$\leq 7.5\%$																																												
		$\leq 10\%$	0805 $\geq 0.33\mu F$ , 1206 $\geq 1\mu F$ , 1210 $\geq 4.7\mu F$																																											
		$\leq 15\%$	1206 $\geq 4.7\mu F$ , 1210 $\geq 22\mu F$																																											
	16V (C < 1.0 $\mu F$ )	$\leq 10\%$																																												
	16V (C $\geq 1.0\mu F$ )	$\leq 12.5\%$																																												
$\leq 20\%$		0805 $\geq 3.3\mu F$ ; 1206 $\geq 10\mu F$ ; 1210 $\geq 22\mu F$ ; 1812 $\geq 47\mu F$ ;																																												
10V	$\leq 20\%$																																													
		I.R.	1000M $\Omega$ or 50 $\Omega$ *F (Whichever is smaller)																																											

No.	Item	Performance		Test or inspection method			
(13)	Temperature cycle	External appearance	No mechanical damage.		The capacitor shall be subject 5 cycles according to four heat treatments listed in the following table. Then Leave the capacitors in ambient condition for the following time before measurement. Class I: 24±2 hours Class II: 48±4 hours		
		Cap. change (ΔC/C)	NPO: ±2.5% or ±0.25pFmax. ( Whichever is larger) X7R: ±7.5% Y5V: ±20%				
		D.F.	To meet initial standard value				
		I.R.	10000MΩ min. or 500Ω*F (Whichever is smaller)				
				Step	Temperature (°C)	Duration (min.)	
				1	Min. Operation Temp.±3	30±3	
				2	Room Temp. (25°C)	2 ~ 3	
				3	Max. Operation Temp.±3	30±2	
				4	Room Temp. (25°C)	2 ~ 3	
				*Preconditioning : (only for Class 2): Perform a heat treatment at 150 +0-10°C for one hour and then let sit for 48±4 hours at room			

### 8. Operating and storage environment:

The insulating coating of capacitors does not form a perfect seal; therefore, do not use or store capacitors in a corrosive atmosphere, especially where chloride gas, sulfide gas, acid, alkali, salt or the like are present. Also avoid exposure to moisture. Before cleaning, bonding or molding this product, verify that these processes do not affect product quality by testing the performance of a cleaned, bonded or molded product in the intended equipment. Store the capacitors where the temperature and relative humidity do not exceed 5 to 40 degrees centigrade and 20 to 70%. Use capacitors within 6 months after delivery.

### 9. Description:

Radial-Leaded, Epoxy-Dipped Multilayer ceramic capacitors are built by superior moisture and shock resistant Epoxy coating, can be supplied in both bulk or tape package for automatic insertion in printed circuit board. But must to avoid effect of external force when the capacitors are used automatic insertion because the inner chips are very weak and easy broken.

Our RD series capacitors have wide application in computer, data Processor, telecom communication, industrial control, and instrumentation equipment, etc.

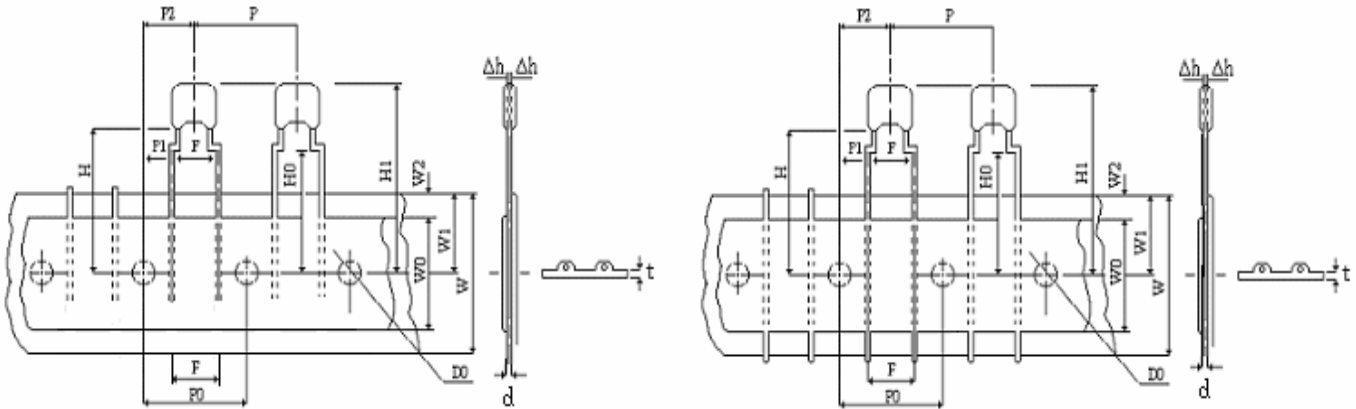
(Epoxy coated: Flame resistance for UL94 V-0 Approved)

### 10. Features:

- (1) Enhanced environmental protection coating.
- (2) COG (NPO) 、X7R 、Y5V characteristic.
- (3) Variety of Lead configuration.

### 11. Taping Figure and Specification: (RD21)

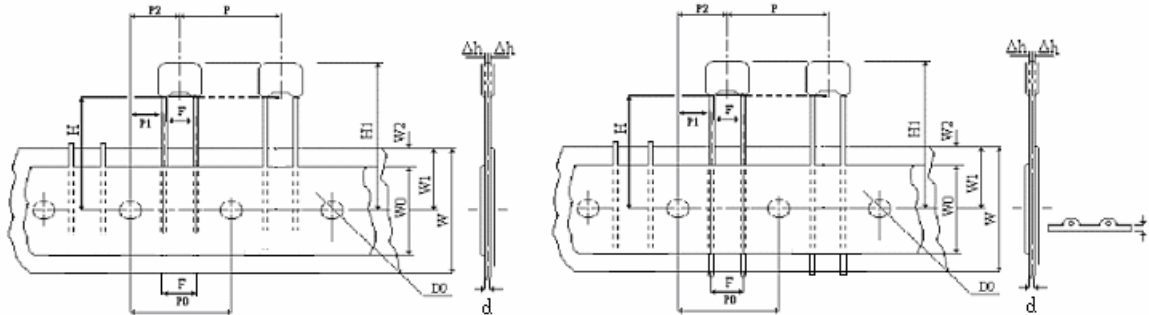
(Unit: mm)



Description	Symbol	Dimension	Remarks
Pitch Of Component	P	12.7±1.0	
Feed Hold Pitch	P0	12.7±0.3	Cumulative Pitch Error : ±1.0 Mm/20 Pitches
Feed Hold Center to Lead	P1	3.85±0.7	
Feed Hold Center to Component Center	P2	6.35±1.3	
Lead diameter	d	0.5±0.05	
Lead To Lead Spacing	F	5.0 ±0.8	To Lead Tip Within Tolerance
Component Alignment, F-R	Δh	2.0 Max	The Alignment From The Center Of The Lead Is±1.0mm
Tape Width	W	18.0+1.0/-0.5	
Adhesive Tape Width	W0	11.0 Min.	
Hole Position	W1	9.0±0.5	
Adhesive Tape Position	W2	3.0 max.	
Height Of Bottom Body From Tape Center	H	18.0+2.0/-0	H+12.5mm≤H1
Lead-Wire Clinch Height	H0	16.0±0.5	6.5≤H0-W1
Component Height	H1	32.25 Max.	
Feed Hole Diameter	D0	4.0±0.2	
Tape Thickness	t	0.6±0.3	

**12. Taping Figure and Specification: (RD20)**

(Unit: mm)



Unit: mm

Description	Symbol	Dimension	Remarks
Pitch Of Component	P	12.7±1.0	
Feed Hold Pitch	P0	12.7±0.3	Cumulative Pitch Error : ±1.0 Mm/20 Pitches
Feed Hold Center to Lead	P1	5.1±0.7	
Feed Hold Center to Component Center	P2	6.35±1.3	
Lead diameter	d	0.5±0.05	
Lead To Lead Spacing	F	2.5 ±0.8	To Lead Tip Within Tolerance
Component Alignment, F-R	Δh	2.0 Max	The Alignment From The Center Of The Lead Is±1.0mm
Tape Width	W	18.0+1.0/-0.5	
Adhesive Tape Width	W0	11.0 Min.	
Hole Position	W1	9.0±0.5	
Adhesive Tape Position	W2	3.0 max.	
Lead-Wire Clinch Height from bottom of capacitor to the hold center	H	18.0±0.5	
Component Height	H1	32.25 Max.	
Feed Hole Diameter	D0	4.0±0.2	
Tape Thickness	t	0.6±0.3	

**13. Packing quantity :**

Chipsize	Taping type		Bulk type
	Quantity per reel	Quantity per box	Quantity per bag
0805	2,000	2,000	1,000
1206,1210,1812	1,500	1,500	1,000

**14. Size code and capacitance (pF) available:**

Dielectric	Size	NPO																				
		0805				1206																
		50	100	200	250	50	100	200	250	500	630	1000										
1.0pF (010)	B	B	B	B																		
1.2pF (1R2)	B	B	B	B		B	B															
1.5pF (1R5)	B	B	B	B		B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B
1.8pF (1R8)	B	B	B	B		B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B
2.2pF (2R2)	B	B	B	B		B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B
2.7pF (2R7)	B	B	B	B		B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B
3.3pF (3R3)	B	B	B	B		B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B
3.9pF (3R9)	B	B	B	B		B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B
4.7pF (4R7)	B	B	B	B		B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B
5.6pF (5R6)	B	B	B	B		B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B
6.8pF (6R8)	B	B	B	B		B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B
8.2pF (8R2)	B	B	B	B		B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B
10pF (100)	B	B	B	B		B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B
12pF (120)	B	B	B	B		B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B
15pF (150)	B	B	B	B		B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B
18pF (180)	B	B	B	B		B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B
22pF (220)	B	B	B	B		B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B
27pF (270)	B	B	B	B		B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B
33pF (330)	B	B	B	B		B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B
39pF (390)	B	B	B	B		B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B
47pF (470)	B	B	B	B		B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B
56pF (560)	B	B	B	B		B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B
68pF (680)	B	B	B	B		B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B
82pF (820)	B	B	B	B		B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B
100pF (101)	B	B	B	B		B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B
120pF (121)	B	B	B	B		B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B
150pF (151)	B	B	B	B		B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B
180pF (181)	B	B	B	B		B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B
220pF (221)	B	B	B	B		B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B
270pF (271)	B	B	B	B		B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B
330pF (331)	B	B	B	B		B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B
390pF (391)	B	B	B	B		B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B
470pF (471)	B	B	B	B		B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B
560pF (561)	B	B	B	B		B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B
680pF (681)	B	B	B	B		B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B
820pF (821)	B	B	B	B		B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B
1000pF (102)	B	B	B			B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B
1200pF (122)	B	B				B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B
1500pF (152)	B	B				B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B
1800pF (182)	B	B				B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B
2200pF (222)	B	B				B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B
2700pF (272)	B	B				B	B															
3300pF (332)	B	B				B	B															
3900pF (392)	B	B				B	B															
4700pF (472)	B	B				B	B															
5600pF (562)	B					B	B															
6800pF (682)	B					B	B															
8200pF (822)	B					B	B															
0.01uF (103)	B					B																

Dielectric	Size	X7R																				
		0805				1206																
		50	100	200	250	50	100	200	250	500	630	1000										
100pF (101)	B	B	B	B																		
120pF (121)	B	B	B	B																		
150pF (151)	B	B	B	B		B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B
180pF (181)	B	B	B	B		B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B
220pF (221)	B	B	B	B		B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B
270pF (271)	B	B	B	B		B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B
330pF (331)	B	B	B	B		B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B
390pF (391)	B	B	B	B		B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B
470pF (471)	B	B	B	B		B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B
560pF (561)	B	B	B	B		B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B
680pF (681)	B	B	B	B		B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B
820pF (821)	B	B	B	B		B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B
1000pF (102)	B	B	B	B		B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B
1200pF (122)	B	B	B	B		B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B
1500pF (152)	B	B	B	B		B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B
1800pF (182)	B	B	B	B		B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B
2200pF (222)	B	B	B	B		B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B
2700pF (272)	B	B	B	B		B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B
3300pF (332)	B	B	B	B		B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B
3900pF (392)	B	B	B	B		B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B
4700pF (472)	B	B	B	B		B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B
5600pF (562)	B					B	B															
6800pF (682)	B					B	B															
8200pF (822)	B					B	B															
0.01uF (103)	B					B																
0.1uF (104)	B	B				B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B	B
0.12uF (124)	B					B	B															
0.15uF (154)	B					B	B															
0.18uF (184)	B					B	B															
0.22uF (224)	B					B	B															
0.27uF (274)	B					B	B															
0.33uF (334)	B					B	B															
0.39uF (394)	B					B	B															
0.47uF (474)	B					B	B															
0.56uF (564)						B	B															
0.68uF (684)						B	B															
0.82uF (824)						B	B															
1.0uF (105)						B																

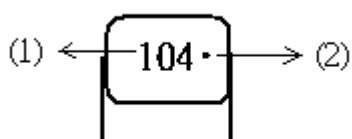
☆ The letter in cell is expressed the symbol of product terminations. B: (Cu/Ni/Sn)  
 ☆ RD21 type can use Mlcc size 0805 and 1206, but RD20 type can only use Mlcc size 0805.

Dielectric		Y5V													
Size		0805						1206							
Voltage (VDC)		10	16	25	50	100	200	250	10	16	25	50	100	200	250
Capacitance	0.01uF (103)	B	B	B	B	B	B	B	B	B	B	B	B	B	B
	0.015uF (153)	B	B	B	B	B	B	B	B	B	B	B	B	B	B
	0.022uF (223)	B	B	B	B	B	B	B	B	B	B	B	B	B	B
	0.033uF (333)	B	B	B	B	B	B	B	B	B	B	B	B	B	B
	0.047uF (473)	B	B	B	B	B	B	B	B	B	B	B	B	B	B
	0.068uF (683)	B	B	B	B	B	B	B	B	B	B	B	B	B	B
	0.1uF (104)	B	B	B	B	B			B	B	B	B	B	B	B
	0.15uF (154)	B	B	B	B				B	B	B	B	B	B	B
	0.22uF (224)	B	B	B	B				B	B	B	B	B		
	0.33uF (334)	B	B	B	B				B	B	B	B			
	0.47uF (474)	B	B	B	B				B	B	B	B			
	0.68uF (684)	B	B	B	B				B	B	B	B			
	1.0uF (105)	B	B	B	B				B	B	B	B			
	1.5uF (155)	B	B						B	B	B				
	2.2uF (225)	B	B	B					B	B	B	B			
	3.3uF (335)	B	B						B	B	B				
	4.7uF (475)	B	B	B					B	B	B				
	6.8uF (685)	B							B	B					
10uF (106)	B							B	B	B					
22uF (226)								B							

- ☆ The letter in cell is expressed the symbol of product terminations. B: (Cu/Ni/Sn)
- ☆ RD21 type can use Mlcc size 0805 and 1206, but RD20 type can only use Mlcc size 0805.

### 15. Marking:

Rated voltage (VDC)	10	16	25	50	100	200	250	500	630	1000	2000	3000
Marking	$\overline{104}$	$10\overline{4}$	$\overline{\overline{104}}$	104	<u>104</u>	<u>104</u>	104	<u>104</u>	$\overline{\overline{104}}$	$\sim 104$	$104 \sim$	$\overset{A}{104}$



- (1) Rated capacitance: Identified by 3-figure code.
- (2) Halogen and Pb free: There is a “•” beside the capacitance code when the coating resin is Halogen and Pb free Epoxy.

单击下面可查看定价，库存，交付和生命周期等信息

[>>Walsin Technology\(华新科技\(华科\)\)](#)

[>>点击查看相关商品](#)